CLAIMS:

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- a class E amplifier having a first transistor;
- a second transistor controlling a current path in parallel to the first transistor; and a controller to control the first and second transistors.
- 2. The apparatus of claim 1, wherein the first and second transistors comprise metal oxide semiconductor field-effect transistors (MOSFET's), and further wherein the second transistor has a source connected to ground and a drain connected to a drain of the first transistor by a resistor.
- 3. The apparatus of claim 1, wherein the apparatus produces an amplitude modulated signal in response to the controller by:

for a first period of time, simultaneously switching the first transistor at a frequency and deactivating the second transistor; and

for a second period of time, simultaneously deactivating the first transistor and activating the second transistor.

- 4. The apparatus of claim 3, wherein the frequency is at least 13.56 megahertz.
 - 5. The apparatus of claim 1, wherein the class E amplifier includes an inductor supplying current to the first transistor, and a shunt capacitor connected in parallel to the first transistor.

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- 6. An amplifier comprising:
 - a first transistor;
 - an inductor coupling the first transistor to a supply voltage via a first resistor;
 - a shunt capacitor connected in parallel to the first transistor;
- a second transistor connected to the inductor by a second resistor, wherein the second transistor controls a current path in parallel to the first transistor and the capacitor;
 - a third transistor connected in parallel to the first resistor; and

a controller coupled to the first, second and third transistors.

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- 7. The amplifier of claim 6, wherein the controller selectively activates the first and second transistors.
- 8. The amplifier of claim 6, wherein the controller activates and deactivates the first transistor at a frequency, and activates and deactivates the second transistor.
- 9. The amplifier of claim 8, wherein the frequency is at least 13.56 megahertz.
- The amplifier of claim 6, wherein the controller activates and deactivates the first 10. transistor at a frequency, and activates and deactivates the third transistor.
- 11. The amplifier of claim 10, wherein the frequency is at least 13.56 megahertz.
- An apparatus comprising: a class E amplifier having a first transistor and an inductor coupling the first
- a second transistor connected in parallel to the first resistor; and a controller coupled to the first and second transistors.

transistor to a supply voltage via a first resistor;

- 13. The apparatus of claim 12, wherein the controller activates and deactivates the first transistor at a frequency, and activates and deactivates the second transistor.
- 14. 25 The apparatus of claim 13, wherein the frequency is at least 13.56 megahertz.
- 15. The apparatus of claim 12, wherein the amplifier further comprises: a shunt capacitor connected in parallel to the first transistor; and a third transistor controlling a current path in parallel to the first transistor and the capacitor. 30

16. The apparatus of claim 15, wherein the controller selectively activates the first and third transistors.							
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